

SANYO**SB007W03C**

Schottky Barrier Diode (Twin Type - Cathode Common)

30V, 70mA Rectifier**Applications**

- High frequency rectification (switching regulators, converters, choppers).

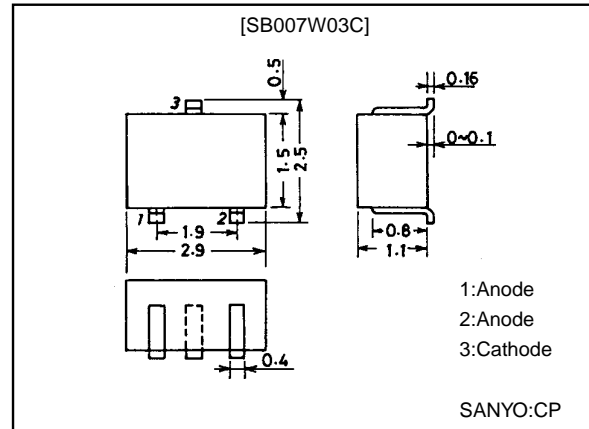
Features

- Low forward voltage ($V_F \text{ max}=0.55\text{V}$).
- Fast reverse recovery time ($t_{rr} \text{ max}=10\text{ns}$).
- Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.

Package Dimensions

unit:mm

1169A

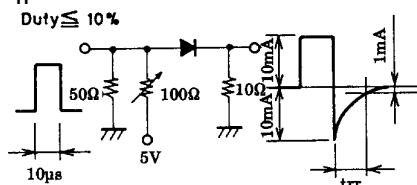
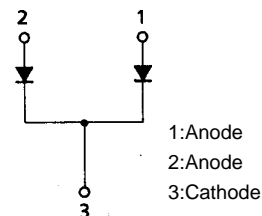
**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

| Parameter | Symbol | Conditions | Ratings | Unit |
|---|-----------|-------------------------|-------------|------------------|
| Repetitive Peak Reverse Voltage | V_{RRM} | | 30 | V |
| Non-repetitive Peak Reverse Surge Voltage | V_{RSM} | | 35 | V |
| Average Output Current | I_O | | 70 | mA |
| Surge Forward Current | I_{FSM} | 50Hz sine wave, 1 cycle | 2 | A |
| Junction Temperature | T_J | | -55 to +125 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | | -55 to +125 | $^\circ\text{C}$ |

Electrical Characteristics at $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---------------------------|----------------|--|---------|-----|------|--------------------|
| | | | min | typ | max | |
| Reverse Voltage | V_R | $I_R=20\mu\text{A}$ | 30 | | | V |
| Forward Voltage | V_F | $I_F=70\text{mA}$ | | | 0.55 | V |
| Reverse Current | I_R | $V_R=15\text{V}$ | | | 5 | μA |
| Interterminal Capacitance | C | $V_R=10\text{V}$, $f=1\text{MHz}$ | | 3.0 | | pF |
| Reverse Recovery Time | t_{rr} | $I_F=I_R=10\text{mA}$, See specified Test Circuit | | | 10 | ns |
| Thermal Resistance (1) | $R_{th(j-a)1}$ | | | 620 | | $^\circ\text{C/W}$ |
| Thermal Resistance (2) | $R_{th(j-a)2}$ | Mounted on Cu-foild area of $16\text{mm}^2 \times 0.2\text{mm}$ on glass epoxy board | | 430 | | $^\circ\text{C/W}$ |

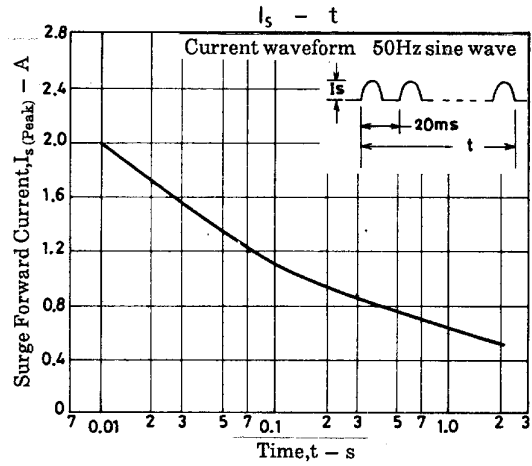
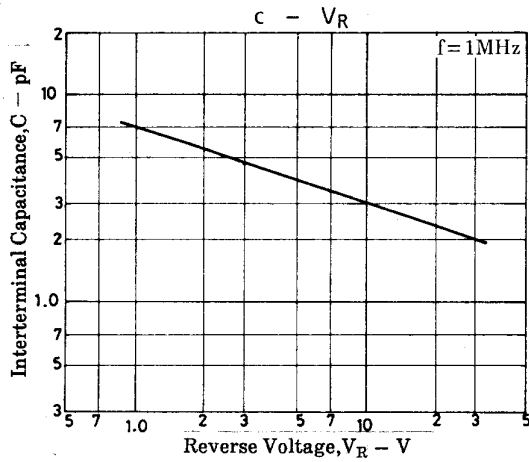
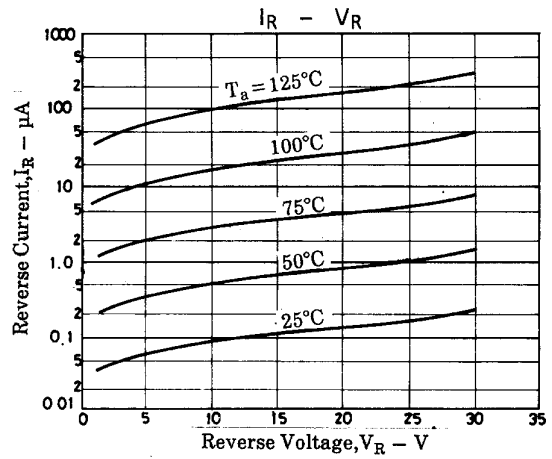
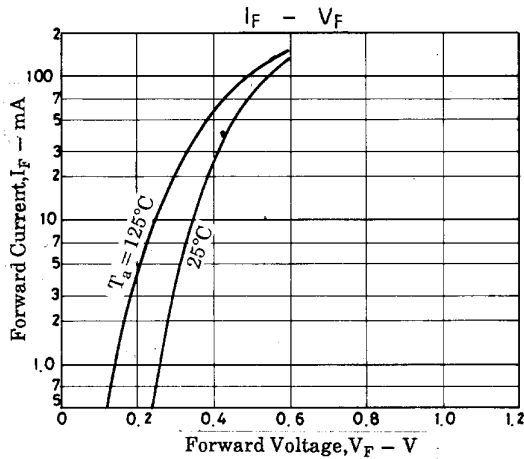
Marking : K

 t_{rr} Test Circuit**Electrical Connection**

SANYO Electric Co.,Ltd. Semiconductor Business Headquarters
TOKYO OFFICE, Tokyo Bldg., 1-10, Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

62098HA (KT)/DI096GI/1269TA, TS No.2936-1/2

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